

Green Products

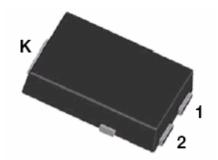
MBR545SL SCHOTTKY RECTIFIER

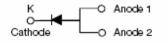
Applications:

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Center tap configuration

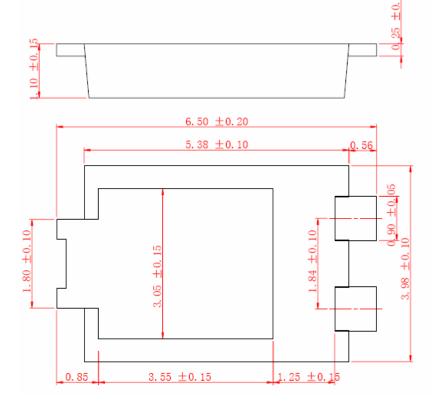
Features:

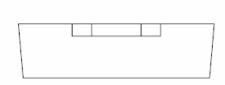
- Designed as Bypass Diodes for Solar Panels
- High Forward Surge Capability
- Ultra Low Forward Voltage Drop
- Excellent High Temperature Stability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- · Additional testing can be offered upon request





Mechanical Dimensions: In mm





TO-277B

[•] Weiqi Street, Airport Development Zone, Jiangning District, Nanjing, China 211113 🗏 (86) 25-87123907 •

[•] FAX (86) 25-87123900 • World Wide Web Site - http://www.sangdest.com.cn • E-Mail Address - sales@ sangdest.com.cn •



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Marking Diagram:



Where XXXXX is YYWWL

5 = Forward Current (5A) 45 = Reverse Voltage (45V)

SL = Device Type

YY = Year WW = Week L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
MBR545SL	TO-277B(Pb-Free)	5000pcs/ reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	45	V
Average Forward Current	I _{F(AV)}	50% duty cycle @T _C =80°C, rectangular wave form	15	А
Peak One Cycle Non- Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine pulse	275	Α

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Electrical Characteristics:

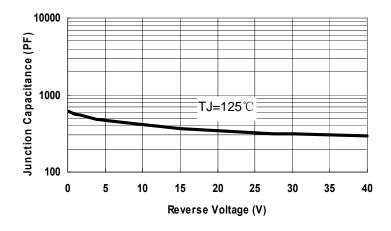
Characteristics	Symbol	Condition	Max.	Units
Forward Voltage Drop	V_{F1}	@ 5A, Pulse, T _J = 25 °C	0.43	V
	V_{F2}	@ 5A, Pulse, T _J = 125 °C	0.40	V
Reverse Current	I _{R1}	$@V_R = \text{rated } V_R$ $T_J = 25 ^{\circ}C$	1.0	mA
	I _{R2}	$@V_R = \text{rated } V_R$ $T_{\perp} = 100 ^{\circ}\text{C}$	50	mA

^{*} Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	T_J	-	-55 to +125	°C
Storage Temperature	T_{stg}	-	-55 to +150	°C
Maximum Thermal Resistance Junction to Case	$R_{\theta JC}$	DC operation	6.0	°C/W
Approximate Weight	wt	-	0.08	g
Case Style		TO-277B		

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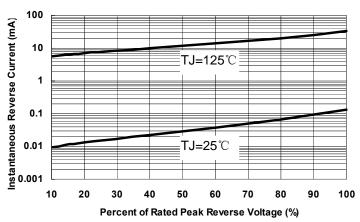


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

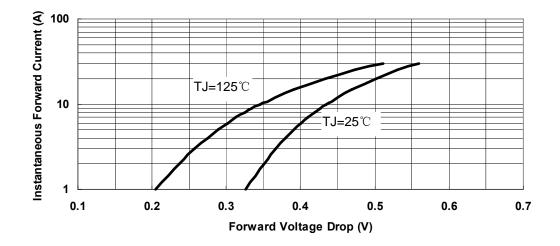


Fig.3-Typical Instantaneous Forward Voltage Characteristics

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MBR545SL

Technical Data Data Sheet N0719, Rev. A

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